



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
40V	8.8mΩ @ V _{GS} = 10V	64.8A
	$13m\Omega @ V_{GS} = 5V$	53.3A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

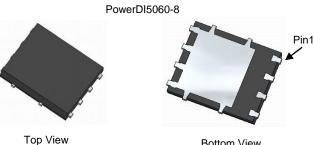
- **Brushless DC Motor Control**
- **DC-DC Converters**
- Load Switch

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching, Test in Production -Ensures More Reliable And Robust End Application
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.097 grams (Approximate)



Bottom View

D 0 sГ s sſ G G S Top View Internal Schematic

Pin Configuration

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Ordering Information (Note 5)

	Part Number	Case	Packaging	
	DMTH4008LPSQ-13	PowerDI5060-8	2,500/Tape & Reel	
Notes:	tes: 1. EU Directive 2002/95/EC (RoHS). 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.			

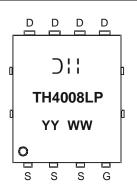
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



PowerDI5060-8

☐ Lanufacturer's Marking TH4008LP = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	40	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current, V _{GS} = 10V (Note 6)	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	ID	14.4 10.2	A
Continuous Drain Current, V_{GS} = 10V (Note 7)	T _C = +25°C T _C = +100°C	ID	64.8 45.8	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	IDM	110	A	
Maximum Continuous Body Diode Forward Current (Note 7)	ls	55.5	A	
Avalanche Current, L = 0.1mH	IAS	22.7	А	
Avalanche Energy, L = 0.1mH		E _{AS}	25.7	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T _A = +25°C	PD	2.99	W
Thermal Resistance, Junction to Ambient (Note 6)		R _{0JA}	50.4	°C/W
Total Power Dissipation (Note 7)	$T_{C} = +25^{\circ}C$	PD	55.5	W
Thermal Resistance, Junction to Case (Note 7)	·	R _{θJC}	2.7	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

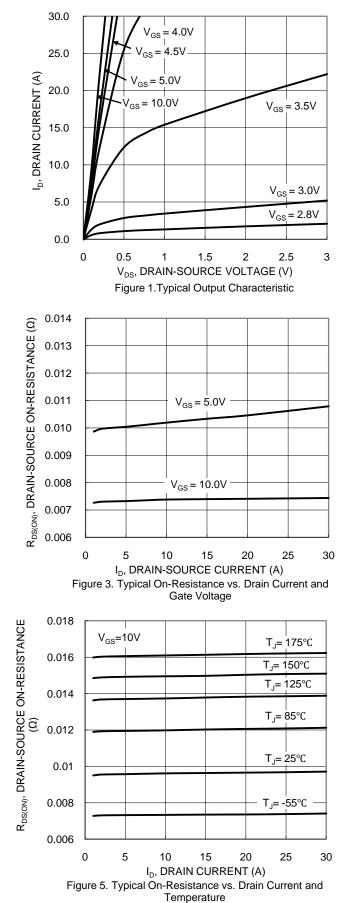
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	40	—	_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	1	1.6	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance		_	7.3	8.8	mΩ	$V_{GS} = 10V, I_D = 10A$	
	R _{DS(ON)}	—	10	13	11152	$V_{GS} = 5V, I_D = 10A$	
Diode Forward Voltage	V _{SD}	_	0.8	1.0	V	$V_{GS} = 0V, I_{S} = 10A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	_	1088	_		$V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	C _{oss}	_	322	—	pF		
Reverse Transfer Capacitance	Crss	—	27	_			
Gate Resistance	Rg	_	2.6	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	7.4			V _{DS} = 20V, I _D = 10A	
Total Gate Charge (V _{GS} = 10V)	Qg	_	15.3	—	-0		
Gate-Source Charge	Q _{gs}	—	2.4	—	nC		
Gate-Drain Charge	Q _{gd}		3.4				
Turn-On Delay Time	t _{D(ON)}	—	4.3	—		$V_{DD} = 20V, V_{GS} = 10V,$ $I_D = 10A, R_G = 6\Omega$	
Turn-On Rise Time	t _R		7.5	_			
Turn-Off Delay Time	t _{D(OFF)}	_	16.7	—	ns		
Turn-Off Fall Time	t _F	—	5.8	—	1		
Body Diode Reverse Recovery Time	t _{RR}		20.2		ns		
Body Diode Reverse Recovery Charge	Q _{RR}	_	8.9	—	nC	$I_F = 10A$, di/dt = 100A/µs	

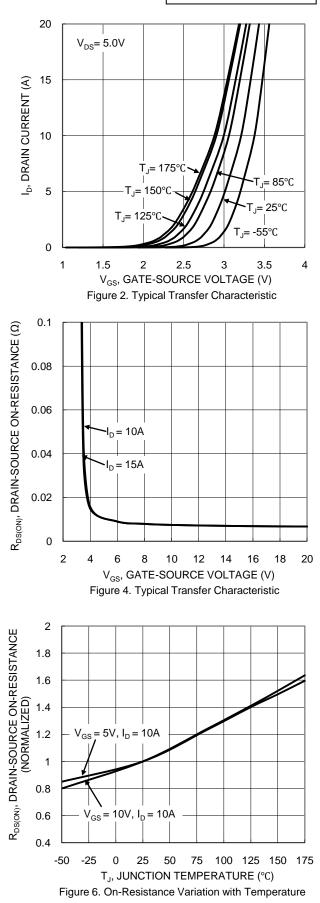
Notes: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

Device interview of a substance of solution, 200 point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.





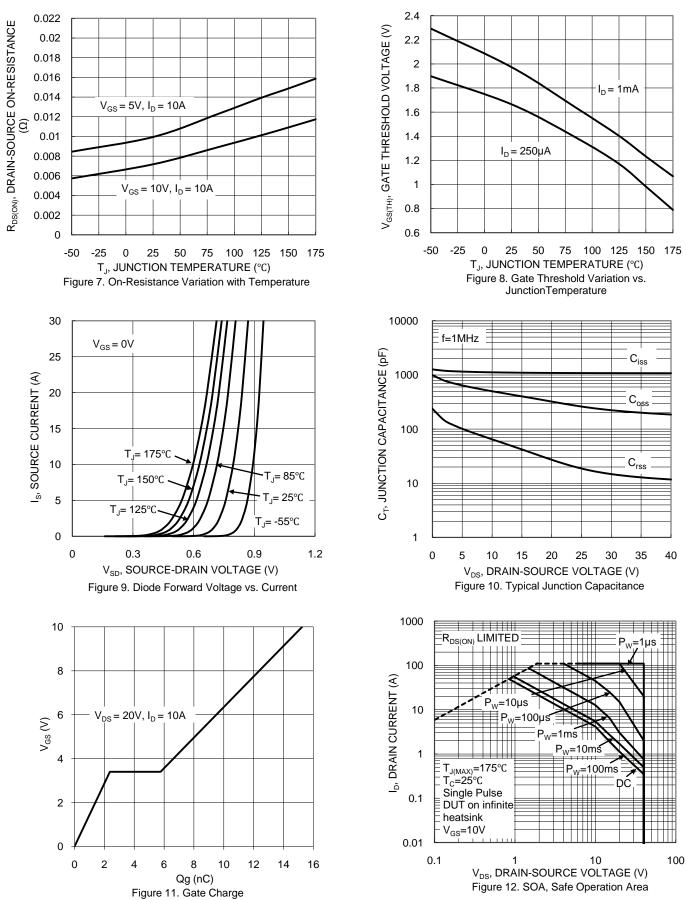




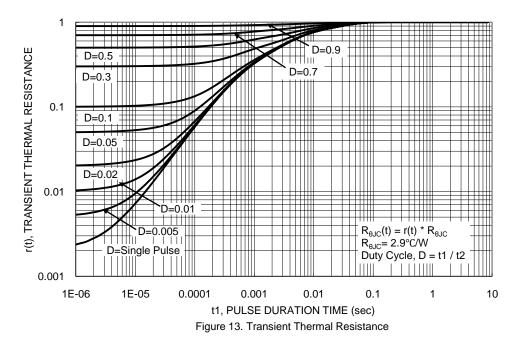
DMTH4008LPSQ Document number: DS40063 Rev. 2 - 2



DMTH4008LPSQ





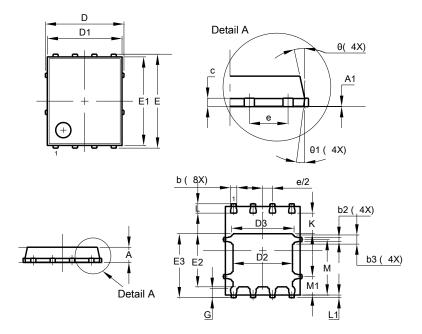




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

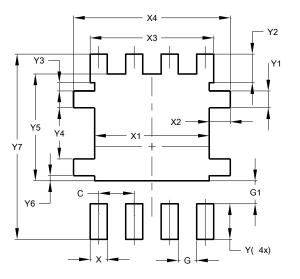


PowerDI5060-8					
Dim	Min Max Typ				
Α	0.90	1.00			
A1	0.00	-			
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	ļ	5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90 4.30 4.10				
E	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC			
G	0.51	0.71	0.61		
К	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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